

ULTRA HIGH VOLTAGE HIGH SPEED DIFFERENTIAL OP-AMP

130

M.S.KENNEDY CORP.

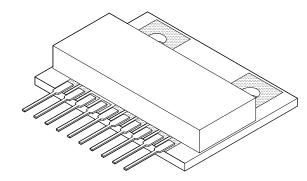
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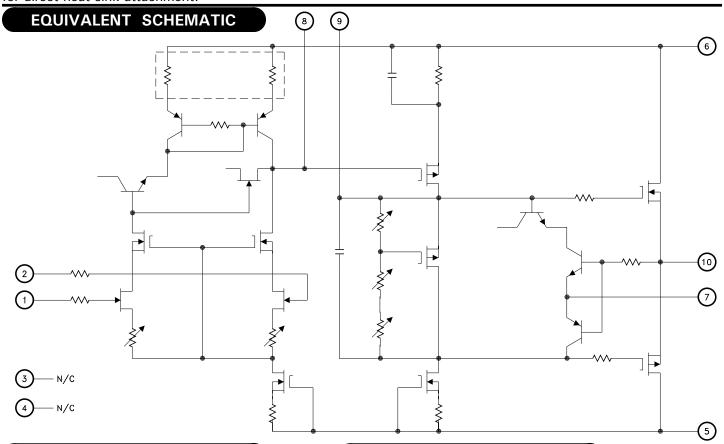
FEATURES:

- Wide Supply Voltage Range 15V to 400V
- Fast Slew Rate 300 V/μS Typ.
- FET Input Accurate DC Specifications
- · Electrically Isolated Case
- · Low Cost Innovative Packaging
- · Very Low Quiescent Current 6mA Typ.
- Output Current to ±200mA
- · Adjustable Current Limit





The MSK 130 is a high speed, high voltage differential amplifier designed for output currents up to ± 200 mA. Since the MSK 130 utilizes external compensation, it exhibits wide bandwidth and greater stability over a wide gain range. High frequency, high voltage instrumentation circuits and electrostatic transducers are just a sample of the applications that the MSK 130 is well suited for. The device is packaged in a 10 pin insulated ceramic SIP with holes for direct heat sink attachment.



TYPICAL APPLICATIONS

- · Ultra-High Voltage Supplies
- · FET Input Instrumentation Amplifiers
- · Electrostatic Deflection
- · Electrostatic Transducers
- · Piezo Transducer Excitation

PIN-OUT INFORMATION

- 1 -Input
 - nut
- 10 Output

2 +Input

- 9 Comp2
- 3 No Connection
- 8 Comp1

Isense

4 No Connection5 -Vcc

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6 + Vcc

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ABSOLUTE MAXIMUM RATINGS

Vcc	Supply Voltage (Total) 400V	T_{ST}	Storage Temperature Range -65°C to +150°C
lоит	Output Current ±300mA	T_LD	Lead Temperature Range 220°C
V_{IND}	Differential Input Voltage ±25V		(10 Seconds)
VINCM	Common Mode Input Voltage ± Vcc	ΤJ	Junction Temperature 150°C
Rтн	Thermal Resistance 15°C/W	T c	Case Operating Temperature Range
	Junction to Case (Output Devices)		(MSK130)55°C to +125°C

ELECTRICAL SPECIFICATIONS

Dougnostou	Test Conditions ①		MSK 130		
Parameter	rest Conditions ()	Min.	Тур. ③	Max.	Units
STATIC					
Supply Voltage Range ② ④	Total +Vcc to -Vcc	20	-	400	V
Quiescent Current	VIN = OV	-	±6	±8	mA
INPUT					
Input Offset Voltage	VIN = OV	-	±0.5	±2.0	mV
Input Offset Voltage Drift ②	VIN = OV	-	± 10	±50	μV/°C
Input Bias Current ②	Vcm=0V Either Input	-	± 10	± 200	pA
Input Offset Current ②	Vcm = 0V	-	10	50	pA
Input Impedance	F = DC	-	10 ¹¹	-	Ω
Input Capacitance	Either Input	-	4.0	-	pF
Power Supply Rejection Ratio ②	$\Delta Vcc = \pm 15V$	-	± 10	± 20	μV/V
Common Mode Rejection Ratio ②	$F = DC VCM = \pm 50V$	80	90	-	dB
Common Mode Range ②	Linear Operation	± Vcc-15	±Vcc-13	-	V
Input Noise Voltage	F = 100KHz	-	1.5	-	μVrms
ОИТРИТ					
Output Voltage Swing	$Iout = \pm 50mA$	±91.5	± 95	-	V
Output Current ②	Within SOA	± 200	± 250	-	mA
Output Resistance	f≤10KHz, No Load	-	50	-	Ω
TRANSFER CHARACTERISTICS					
Slew Rate Limit	Av = 100v/v $Cc = 0pF$	-	300	-	V/μS
Open Loop Voltage Gain ②	F=15Hz Cc=0pF	95	110	-	dB
Settling Time to 0.1%	$RL = 1K\Omega$ 2V step $Cc = 10pF$	-	1	-	μS

NOTES:

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① \pm Vcc = \pm 100V, Tc = 25 °C, Rc = 100 Ω , Cc = 68pF unless otherwise specified.

② Devices shall be capable of meeting the parameter, but need not be tested.

³ Typical parameters are representative of actual device performance but are for reference only.

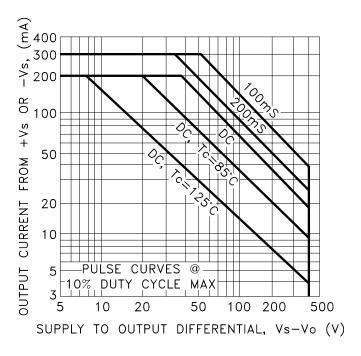
⁴ Maximum supply voltage should be derated 0.625V/°C below 25°C case temperature.

SAFE OPERATING AREA

The output stage of the MSK 130 is fabricated using state of the art complimentary MOSFETs and is free from secondary breakdown limitations. There are two distinct limitations for the output stage:

- 1. The internal wire bonds and the geometry of the MOSFET have a maximum peak current capability of ± 300 mA.
- 2. The junction temperature of each MOSFET should be kept below the maximum rating of 150°C.

The SOA Curves below illustrate various conditions of power dissipation.



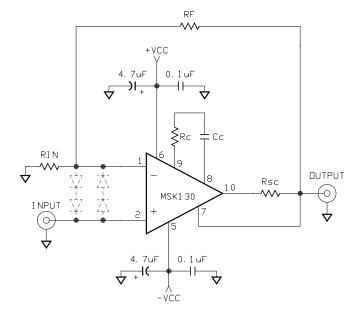
INPUT PROTECTION

The MSK 130 can safely handle up to $\pm 25V$ of differential input voltages. In applications where this may be violated, external protection is required. Four diodes can be used as shown in the typical connection diagram. If leakage current is of concern, use JFETs connected as diodes instead. JFETs will also yield very low capacitance for high speed applications.

CURRENT LIMIT

The MSK 130 has an internal active current limit circuit that can be programmed with a single external resistor Rsc. The value of this resistor should be kept between 2Ω and 150Ω . The following equation is used to select the resistor for a given current limit value:

Rsc = 0.6/ILIMIT (See Typical Connection Diagram)



TYPICAL CONNECTION DIAGRAM

STABILITY AND COMPENSATION

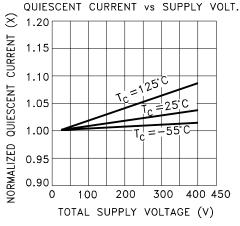
Since the MSK 130 is externally compensated the bandwidth can be optimized for any gain selection. The external compensation components should be located as close to the compensation pins as possible to avoid unwanted oscillations. The capacitor Cc should be rated for the full supply voltage. Use a high quality dielectric such as NPO to maintain a desired compensation over the full operating temperature. Refer to the typical performance curves for a guide to select the desired compensation. Refer to the typical connection diagram for the location of the Rc and Cc components.

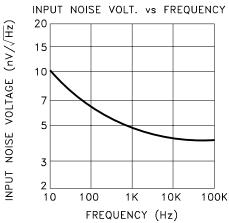
POWER SUPPLIES

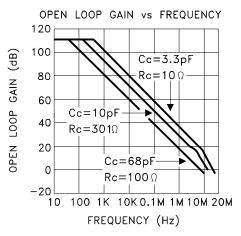
Both the negative and positive power supplies must be effectively decoupled with a high and low frequency bypass circuit to avoid power supply induced oscillation. An effective decoupling scheme consists of a 0.1 microfarad ceramic capacitor in parallel with a 4.7 microfarad tantalum capacitor for each power supply pin to ground. All power supply decoupling capacitors should be placed as close to the package power supply pins as possible (pins 5 and 6).

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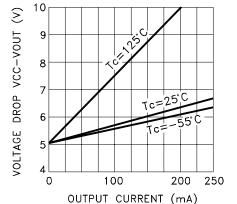
TYPICAL PERFORMANCE CURVES

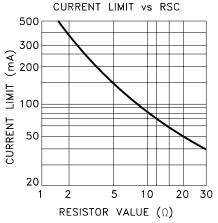


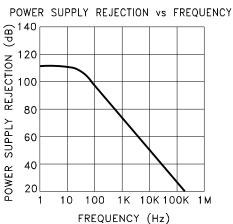


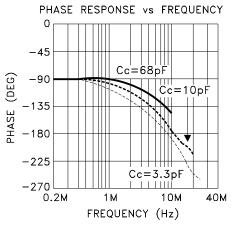


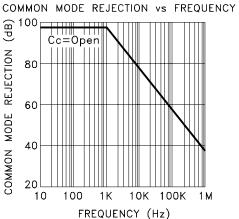






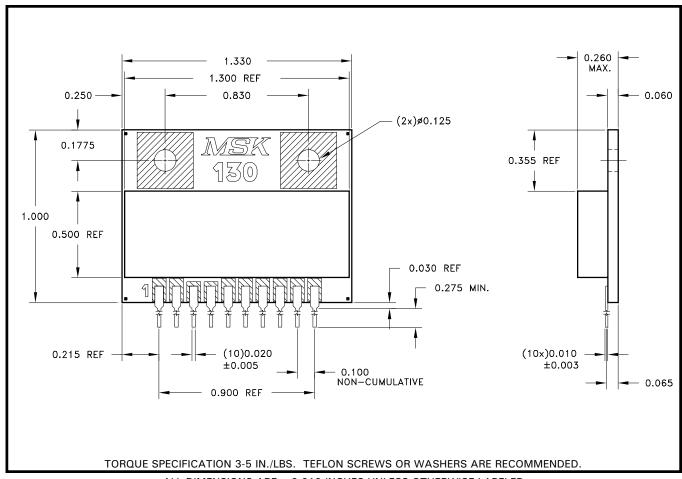






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ALL DIMENSIONS ARE ± 0.010 INCHES UNLESS OTHERWISE LABELED

ORDERING INFORMATION

Part Number	Screening Level
MSK130	Industrial

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